44,00-103- Gp2508

- 1 -

Docket: 0756-711

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT application of)	25Cl
Shunpei YAMAZAKI, ET AL.)	
Serial No. 07/852,517)	Art Unit: 2508
Filed: March 17, 1992)	Examiner: M. Saadat
For: SEMICONDUCTOR MATER-)	· All/4
IAL AND METHOD FOR)	My 1
FORMING THE SAME AND)	CERTIFICATE OF MARING
THIN FILM TRANSISTOR)	deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Commissioner of Patents and Trademarks, Washington, D.C. 20231, on 6/15/93

AMENDMENT

Honorable Commissioner of Patents and Trademarks

Washington, D.C. 20231

JUL 0 9 1993

City 2520

Sir:

In response to the Official Action of March 15, 1993, please amend the above-identified application as follows:

IN THE CLAIMS:

Please amend claims 4, 18 and 20 as follows:

Claim 4, line 2, delete "or YAG laser".

18. (Amended) A thin film transistor comprising an [intrinsic or] at least substantially intrinsic semiconductor included in a channel of said thin 1 103 44.00 CK

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